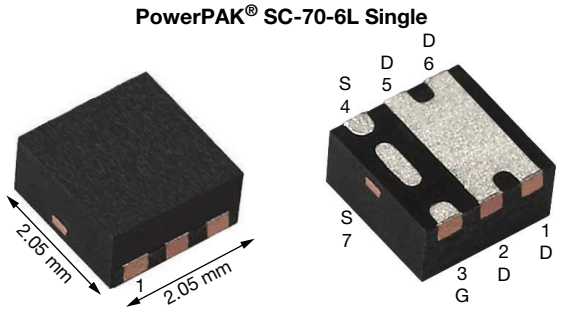
P-Channel 30 V (D-S) MOSFET

PowerPAK® SC-70-6L Single



Top View Bottom View

FEATURES

- TrenchFET® Gen IV p-channel power MOSFET
- Thermally enhanced PowerPAK® SC-70 package
- Very low $R_{DS(on)}$ x area minimizes power loss on limited PCB real estate
- Provides excellent R_{DS}-Q_g Figure-of-Merit (FOM) for switching applications
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

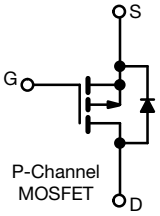
RoHS COMPLIANT
HALOGEN FREE

PRODUCT SUMMARY	
V_{DS} (V)	-30
$R_{DS(on)}$ max. (Ω) at V_{GS} = -10 V	0.0140
$R_{DS(on)}$ max. (Ω) at V_{GS} = -4.5 V	0.0241
Q_g typ. (nC)	8.9
I_D (A)	-30.3
Configuration	Single

Marking code: B9

APPLICATIONS

- Battery charging and management
- Load switch
- DC/DC converters
- Power management in battery-operated, mobile and wearable devices



ORDERING INFORMATION	
Package	PowerPAK SC-70
Lead (Pb)-free and halogen-free	SiA471DJ-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	-30	V
Gate-source voltage		V_{GS}	-20 / +16	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	-30.3	A
	T_C = 70 °C		-24.2	
	T_A =25 °C		-12.9 [a, b]	
	T_A = 70 °C		-10.3 [a, b]	
Pulsed drain current (t = 100 µs)		I_{DM}	-70	
Continuous source-drain diode current	T_C = 25 °C	I_S	-16	
	T_A = 25 °C		-2.9 [a, b]	
Maximum power dissipation	T_C = 25 °C	P_D	19.2	W
	T_C = 70 °C		12.3	
	T_A = 25 °C		3.5 [a, b]	
	T_A = 70 °C		2.2 [a, b]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) [c, d]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient [a, e]	t ≤ 5 s	R_{thJA}	28	36	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	5.3	6.5	

Notes

a. Surface mounted on 1" x 1" FR4 board
b. t = 5 s
c. See solder profile (www.vishay.com/ppg?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
d. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
e. Maximum under steady state conditions is 80 °C/W

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = -250 μA	-30	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = -10 mA	-	-15	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		-	5	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = -250 μA	-1	-	-2.5	V
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = -20 V / +16 V	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = -30 V, V_{GS} = 0 V	-	-	-1	μA
		V_{DS} = -30 V, V_{GS} = 0 V, T_J = 55 °C	-	-	-10	
On-state drain current [a]	$I_{D(on)}$	V_{DS} ≤ -5 V, V_{GS} = 0 V	-10	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = -10 V, I_D = -10 A	-	0.0115	0.0140	Ω
		V_{GS} = -4.5 V, I_D = -7 A	-	0.0185	0.0241	
Forward transconductance [a]	g_{fs}	V_{DS} = -10 V, I_D = -10 A	-	40	-	S
Dynamic [b]						
Input capacitance	C_{iss}	V_{DS} = -15 V, V_{GS} = 0 V, f = 1 MHz	-	1170	-	pF
Output capacitance	C_{oss}		-	570	-	
Reverse transfer capacitance	C_{rss}		-	55	-	
Total gate charge	Q_g	V_{DS} = -15 V, V_{GS} = -10 V, I_D = -12 A	-	18.5	27.8	nC
		V_{DS} = -15 V, V_{GS} = -4.5 V, I_D = -12 A	-	8.9	14	
Gate-source charge	Q_{gs}	V_{DS} = -15 V, V_{GS} = -4.5 V, I_D = -12 A	-	4.4	-	
Gate-drain charge	Q_{gd}		-	2.7	-	
Gate resistance	R_g	f = 1 MHz	0.22	11	22	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = -15 V, R_L = 1.5 Ω, I_D ≅ -10 A, V_{GEN} = -4.5 V, R_g = 1 Ω	-	25	50	ns
Rise time	t_r		-	95	190	
Turn-off delay time	$t_{d(off)}$		-	40	80	
Fall time	t_f		-	18	36	
Turn-on delay time	$t_{d(on)}$	V_{DD} = -15 V, R_L = 1.5 Ω, I_D ≅ -10 A, V_{GEN} = -10 V, R_g = 1 Ω	-	13	26	
Rise time	t_r		-	8	16	
Turn-off delay time	$t_{d(off)}$		-	35	70	
Fall time	t_f		-	15	30	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	T_C = 25 °C	-	-	-16	A
Pulse diode forward current	I_{SM}		-	-	-70	
Body diode voltage	V_{SD}	I_S = -10 A, V_{GS} = 0 V	-	-0.85	-1.2	V
Body diode reverse recovery time	t_{rr}	I_F = -10 A, di/dt = 100 A/μs, T_J = 25 °C	-	21	42	ns
Body diode reverse recovery charge	Q_{rr}		-	8	16	nC
Reverse recovery fall time	t_a		-	9	-	ns
Reverse recovery rise time	t_b		-	12	-	

Notes

a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %

b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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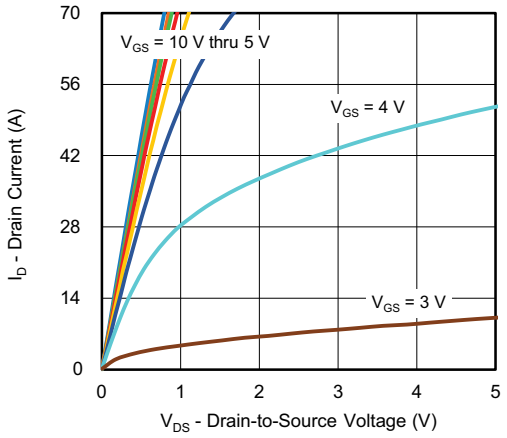
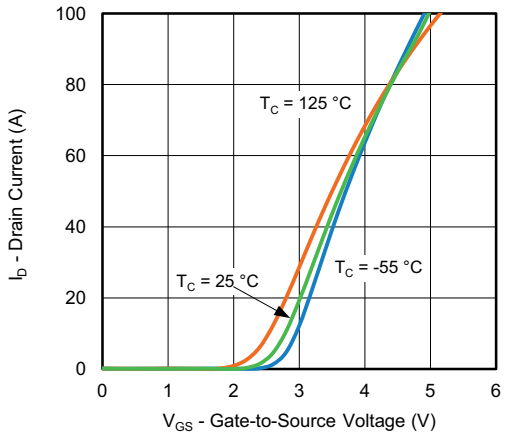
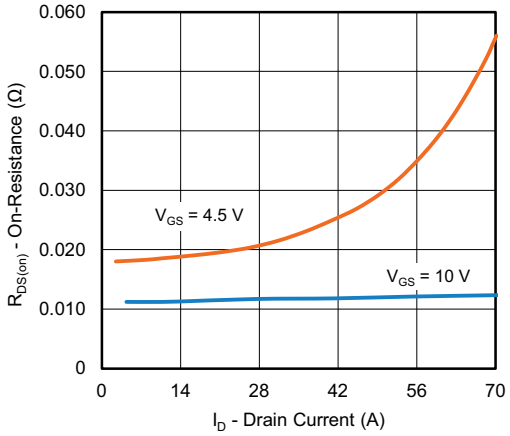


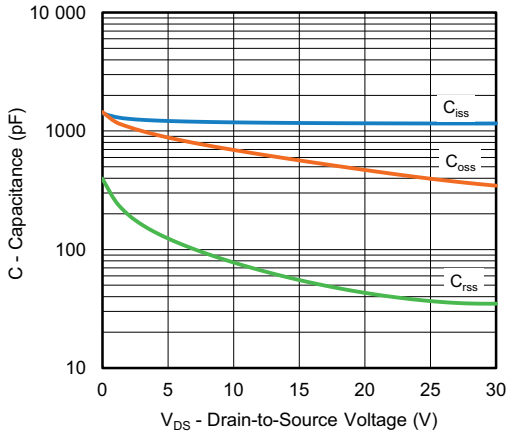
Output Characteristics



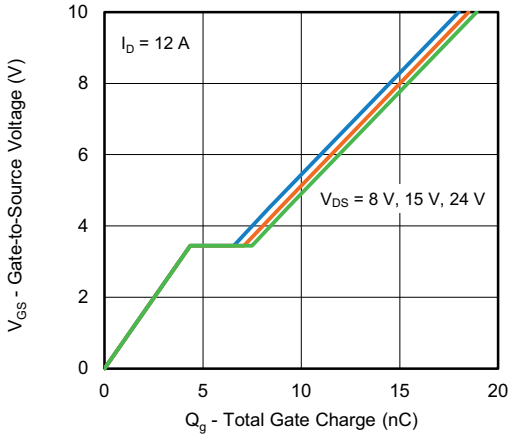
Transfer Characteristics



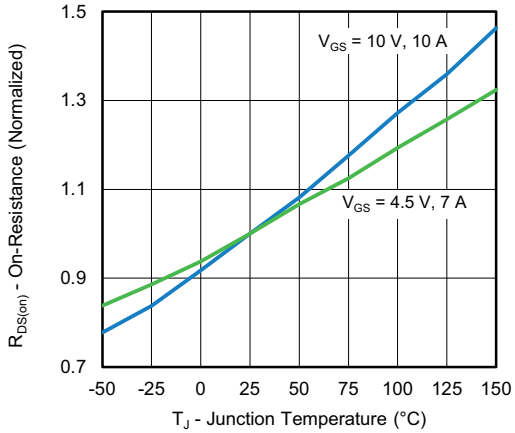
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



Gate Charge



On-Resistance vs. Junction Temperature

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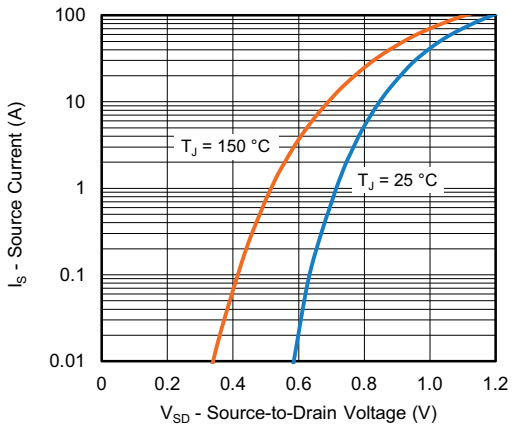
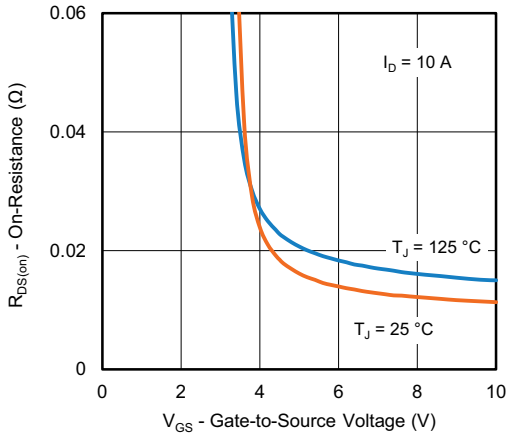
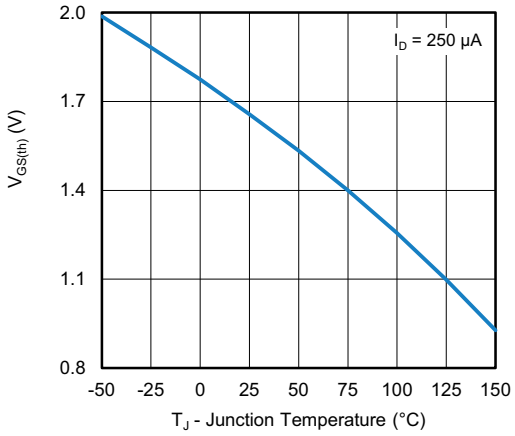


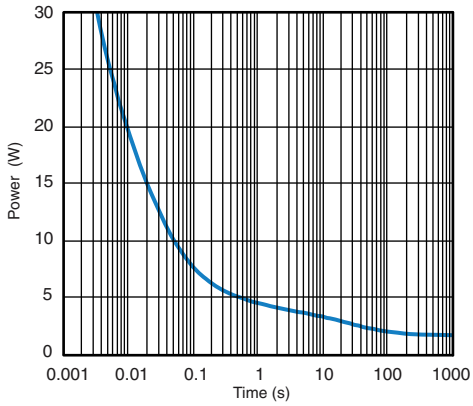
Source-Drain Diode Forward Voltage



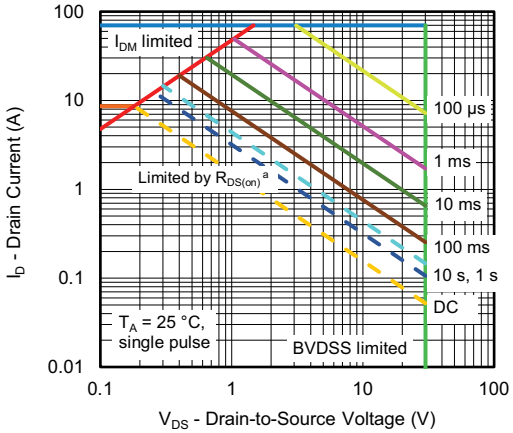
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient

Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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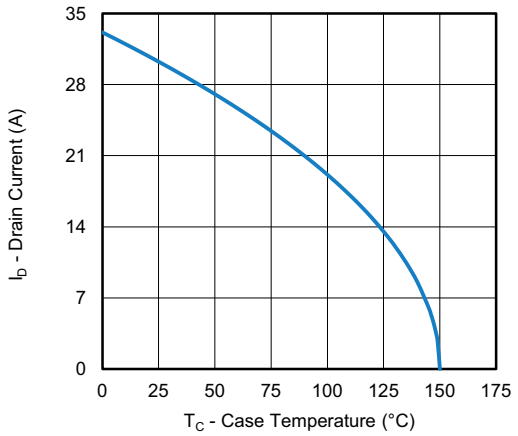
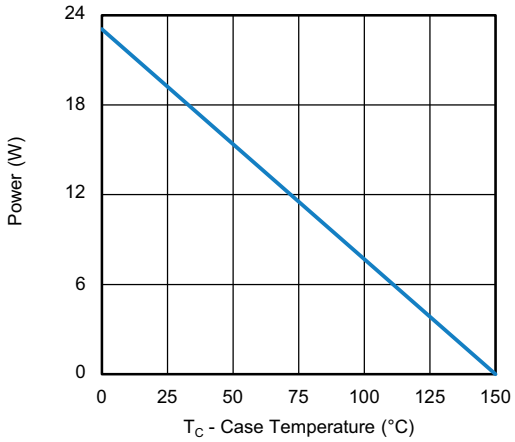
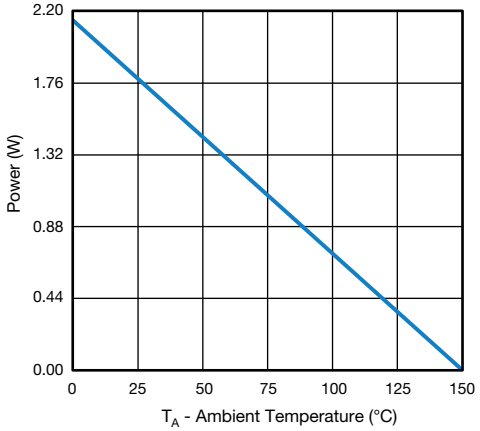


Current Derating [a]



Power, Junction-to-Case



Power, Junction-to-Ambient

Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-ambient thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

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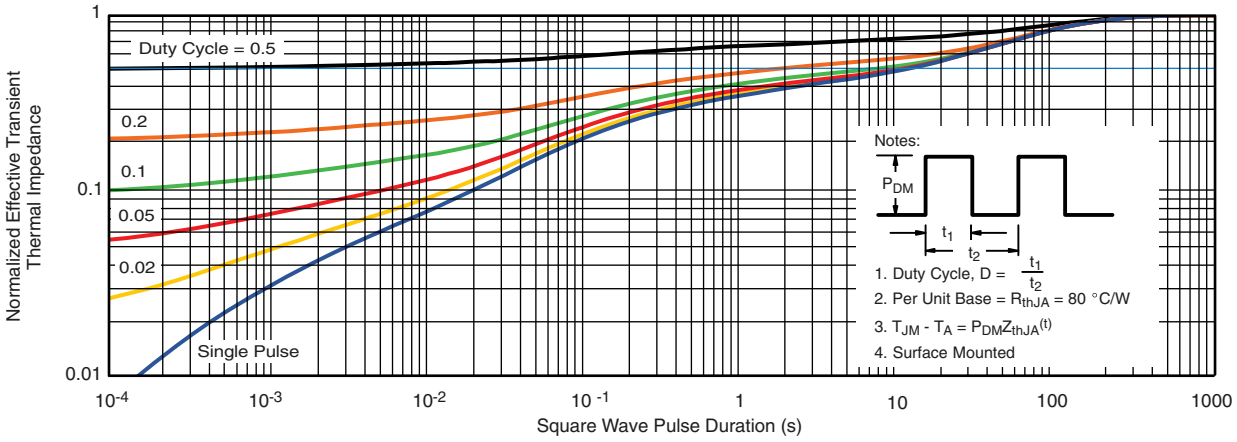
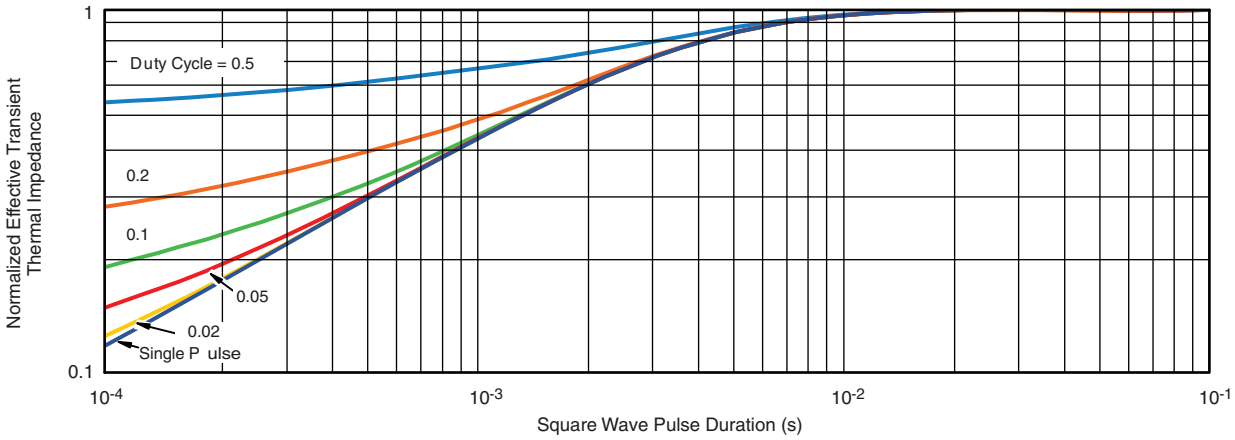


Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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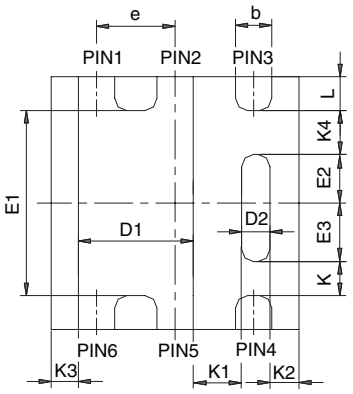
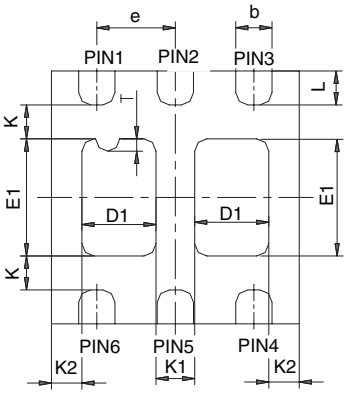
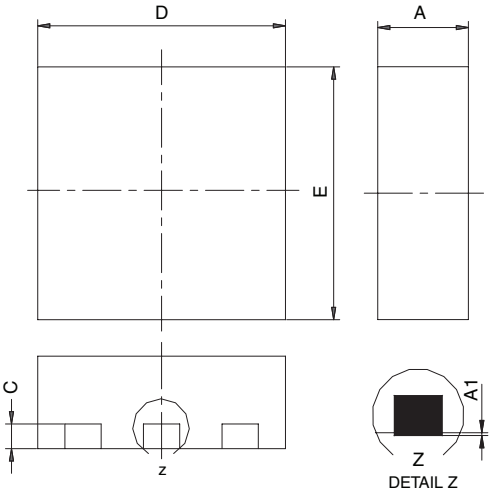
PowerPAK® SC70-6L



BACKSIDE VIEW OF SINGLE



BACKSIDE VIEW OF DUAL

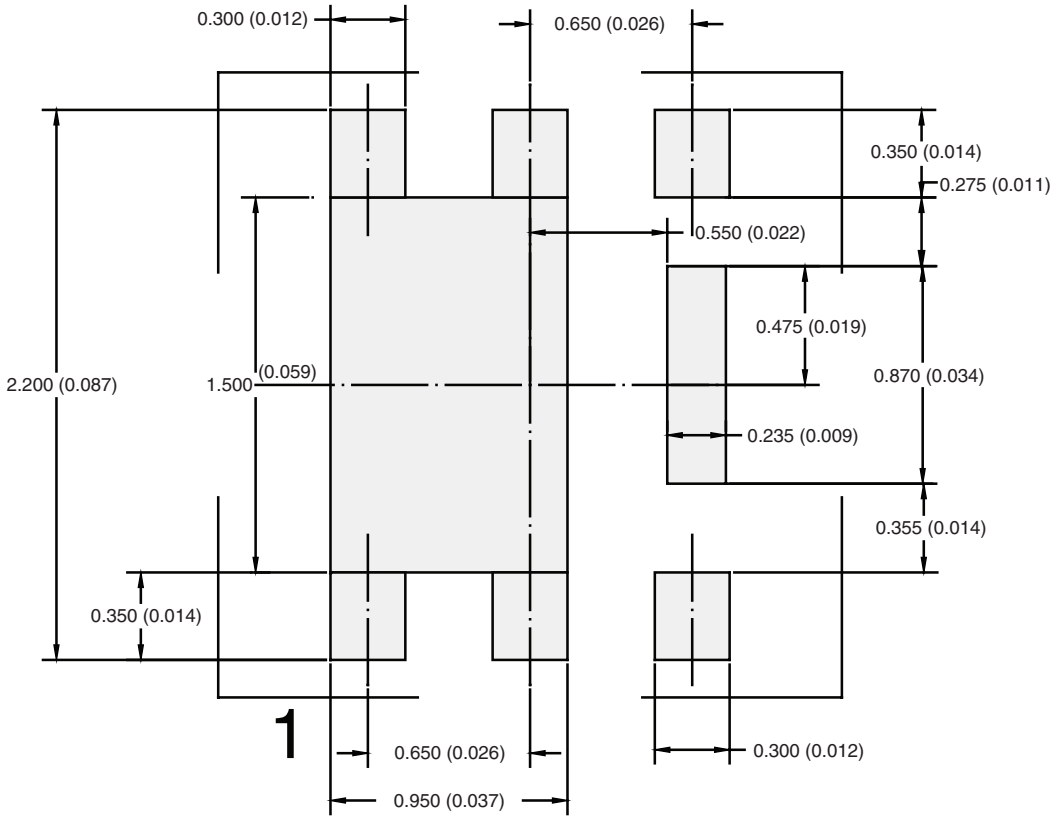


Notes:
1. All dimensions are in millimeters
2. Package outline exclusive of mold flash and metal burr
3. Package outline inclusive of plating

DIM	SINGLE PAD						DUAL PAD					
	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
A	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
C	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
e	0.65 BSC			0.026 BSC			0.65 BSC			0.026 BSC		
K	0.275 TYP			0.011 TYP			0.275 TYP			0.011 TYP		
K1	0.400 TYP			0.016 TYP			0.320 TYP			0.013 TYP		
K2	0.240 TYP			0.009 TYP			0.252 TYP			0.010 TYP		
K3	0.225 TYP			0.009 TYP								
K4	0.355 TYP			0.014 TYP								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
T							0.05	0.10	0.15	0.002	0.004	0.006

ECN: C-07431 – Rev. C, 06-Aug-07
DWG: 5934

RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

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